Silicon P Channel MOS Type (U-MOSⅢ)/Silicon Epitaxial Schottky Barrier Diode

SSM5G10TU

DC-DC Converter Applications

- 1.8-V drive
- Combines a P-channel MOSFET and a Schottky barrier diode in one package.
- Low R_{DS(ON)} and Low V_F

Absolute Maximum Ratings

MOSFET (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V_{DS}	-20	V	
Gate-Source voltage		V_{GSS}	± 8	V	
Drain current	DC	I _D	-1.5	Α	
	Pulse	I _{DP} (Note 2)	-3.0		
Drain power dissipation		P _D (Note 1)	0.5	W	
		t = 10 s	0.8	VV	
Channel temperature		T _{ch}	150	°C	

Schottky Barrier Diode (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Repetitive peak reverse voltage	V_{RRM}	20	V
Average forward current	I _{F(AV)}	0.7	Α
Peak one cycle surge forward current	I _{FSM}	2 (50 Hz)	Α
Junction temperature	Τj	125	°C

1: GATE 4: CATHODE 2: SOURCE 5: DRAIN 3: ANODE UFV JEDEC — JEITA — TOSHIBA 2-2R1A

Weight: 7 mg (typ.)

MOSFET and Diode (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Storage temperature range	T _{stg}	-55 to 125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

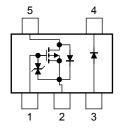
Note 1: Mounted on FR4 board

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ mm}, \text{ Cu pad: } 645 \text{ mm}^2)$

Marking

5 4 KET

Equivalent Circuit (top view)



Start of commercial production 2008-04

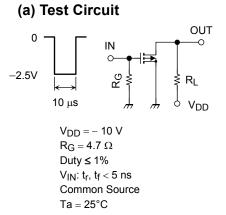
MOSFET

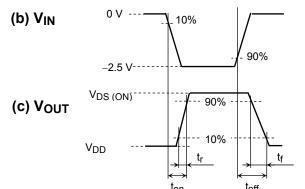
Electrical Characteristics (Ta = 25°C)

Chara	cteristics	Symbol	Test Conditions		Min	Тур.	Max	Unit
Drain-source breakdown voltage		V (BR) DSS	7 60 4		-20	_	_	٧
		V (BR) DSX			-12	_	_	
Drain cutoff curre	nt	I _{DSS}	V _{DS} = -20 V, V _{GS} = 0 V		_	_	-10	μА
Gate leakage curr	ent	I _{GSS}	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$		_	_	±1	μА
Gate threshold vo	Itage	V _{th}	$V_{DS} = -3 \text{ V}, I_D = -1 \text{ mA}$		-0.3	_	-1.0	V
Forward transfer a	admittance	Y _{fs}	$V_{DS} = -3 \text{ V}, I_{D} = -1 \text{ A}$	(Note 2)	1.6	3.2	_	S
Drain-source ON-resistance			I _D = -1.0 A, V _{GS} = -4 V	(Note 2)	_	160	213	mΩ
		R _{DS} (ON)	I _D = -0.8 A, V _{GS} = -2.5 V	(Note 2)	_	210	294	
			I _D = -0.1 A, V _{GS} = -1.8 V	(Note 2)	_	280	430	
Input capacitance		C _{iss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz		_	250	_	pF
Output capacitance		Coss			_	43	_	
Reverse transfer capacitance		C _{rss}		_	35	_		
Total Gate Charge		Qg	V _{DS} = -10 V, I _D = -1.5 A, V _{GS} = -4 V		_	6.4	_	nC
Gate-Source Charge		Q _{gs}			_	4.5	_	
Gate-Drain Charge		Q _{gd}			_	1.9	_	
Switching time	Turn-on time	t _{on}	V _{DD} = -10 V, I _D = -1 A,		_	12	_	
	Turn-off time	t _{off}	$V_{GS} = 0$ to -2.5 V, $R_{G} = 4.7$ S	Ω	_	11.2	_	ns
Drain-source forward voltage		V _{DSF}	I _D = 1.5 A, V _{GS} = 0 V	(Note 2)	_	0.88	1.2	V

Note 2: Pulse test

Switching Time Test Circuit





Precaution

 V_{th} can be expressed as voltage between gate and source when the low operating current value is $I_D = -1$ mA for this product. For normal switching operation, V_{GS} (on) requires a higher voltage than V_{th} and V_{GS} (off) requires a lower voltage than V_{th} .

2

(The relationship can be established as follows: $V_{GS\ (off)} < V_{th} < V_{GS\ (on)}$) Be sure to take this into consideration when using the device.

Schottky Barrier Diode

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Peak forward voltage	V _{FM (1)}	I _F = 0.5 A	_	0.32	0.39	V
Peak forward voltage	V _{FM (2)}	I _F = 0.7 A	_	0.36	0.43	V
Repetitive peak reverse current	I _{RRM}	V _R = 6 V	_	25	150	μА
Junction capacitance	C _T	V _R = 0 V, f = 1 MHz	_	143	_	pF

Precaution

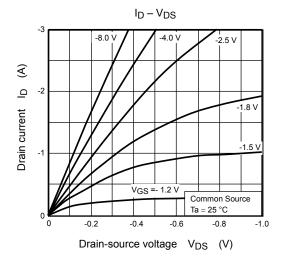
The Schottky barrier diode in this device has large reverse current leakage compared to typical switching diodes. Thus, excessive operating temperature or voltage may cause thermal runaway. To avoid this problem, be sure to take both forward and reverse loss into consideration.

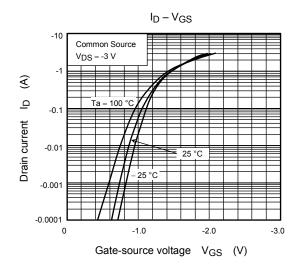
Handling Precaution

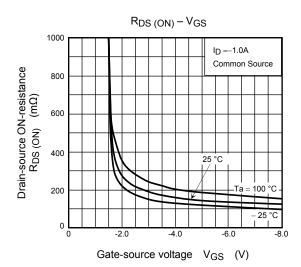
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

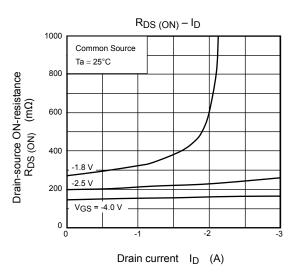
The Channel-to-Ambient thermal resistance $R_{th (ch-a)}$ and the drain power dissipation P_D vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.

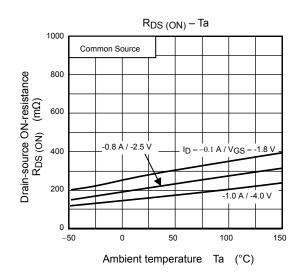
MOSFET

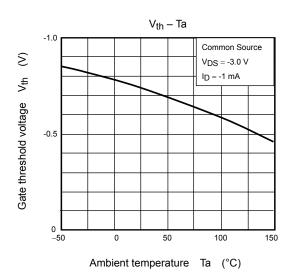




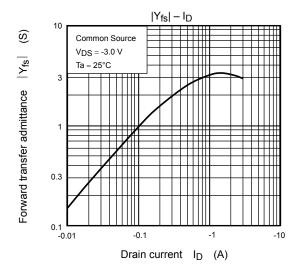


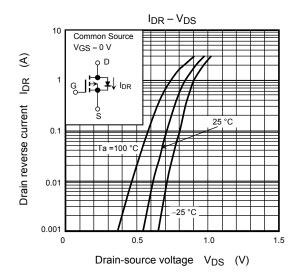


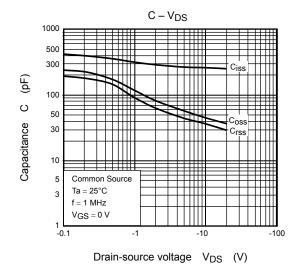


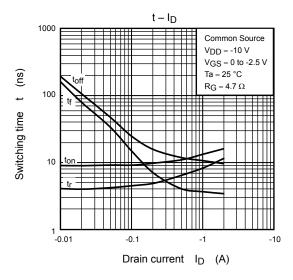


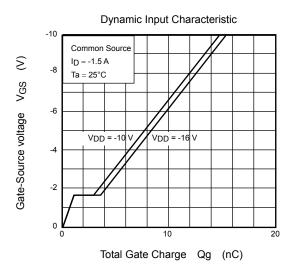
MOSFET



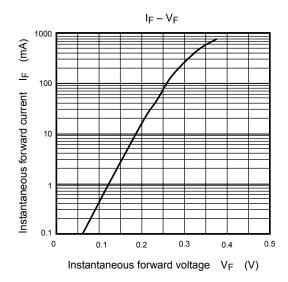


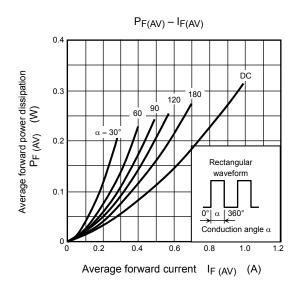


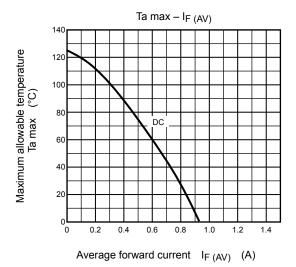


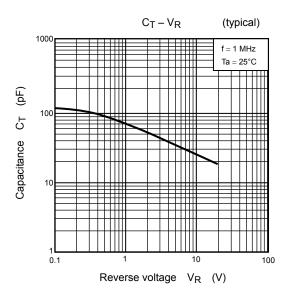


Schottky Barrier Diode

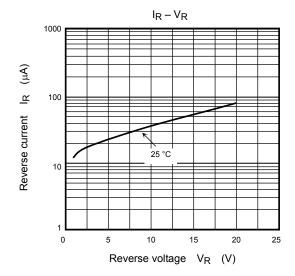


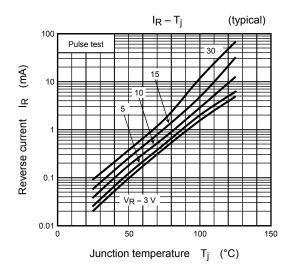


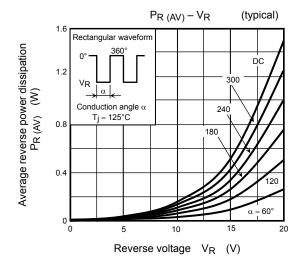




Schottky Diode







RESTRICTIONS ON PRODUCT USE

- Toshiba Corporation, and its subsidiaries and affiliates (collectively "TOSHIBA"), reserve the right to make changes to the information in this document, and related hardware, software and systems (collectively "Product") without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE
 EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH
 MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT
 ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without
 limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, medical equipment, equipment used for
 automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions,
 safety devices, elevators and escalators, devices related to electric power, and equipment used in finance-related fields. IF YOU USE
 PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your
 TOSHIBA sales representative.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
 applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE
 FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY
 WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR
 LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND
 LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO
 SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS
 FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.
 Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES
 OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.